Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

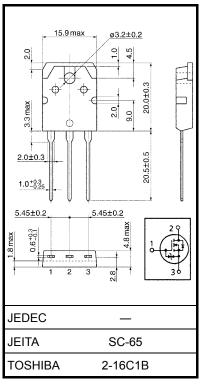
# 2SK3506

Relay Drive and DC-DC Converter Applications Motor Drive Applications

- Low drain-source ON resistance: R<sub>DS (ON)</sub> = 16 mΩ (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 26 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS}$  = 100  $\mu$ A (max) (V<sub>DS</sub> = 30 V)
- Enhancement model:  $V_{th}$  = 1.5 to 3.0 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

## Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	30	V	
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		V <sub>DGR</sub>	30	V	
Gate-source voltage		V <sub>GSS</sub>	±20	V	
Drain current	DC (Note 1)	۱ <sub>D</sub>	45	А	
	Pulse (Note 1)	I <sub>DP</sub>	135	A	
Drain power dissipation (Tc = $25^{\circ}$ C)		PD	100	W	
Single pulse avalanche energy (Note 2)		E <sub>AS</sub>	220	mJ	
Avalanche current		I <sub>AR</sub>	45	А	
Repetitive avalanche energy (Note 3)		E <sub>AR</sub>	10	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to150	°C	



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

## Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	1.25	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	50	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: VDD = 25 V, Tch = 25°C (initial), L = 78  $\mu$ H, IAR = 45 A, RG = 25  $\Omega$ 

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

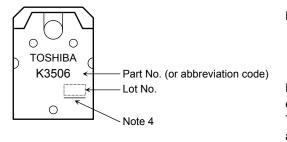
**Electrical Characteristics (Ta = 25°C)** 

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS}=\pm 16~V,~V_{DS}=0~V$			±10	μA
Drain cut-OFF current		I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	—		100	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30		_	V
Gate threshold voltage		V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	1.5		3.0	V
Drain-source ON resistance		R <sub>DS (ON)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 25 \text{ A}$	_	16	20	mΩ
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 25 \text{ A}$	13	26	—	S
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	—	1500	—	pF
Reverse transfer capacitance		C <sub>rss</sub>		_	480	_	
Output capacitance		C <sub>oss</sub>			680	_	
Switching time	Rise time	tr	$V_{GS}^{10 \text{ V}} \downarrow I_D = 25 \text{ A} \\ 0 \text{ V} \downarrow I_D = 25 \text{ A} \\ 0 \text{ V} \downarrow I_D = 25 \text{ A} \\ 0 \text{ V} \downarrow I_D = 25 \text{ A} \\ 0 \text{ V} \downarrow I_D = 0 \text{ V} \text{OUT}$	_	11	_	- ns
	Turn-ON time	t <sub>on</sub>			18		
	Fall time	t <sub>f</sub>			60	_	
	Turn-OFF time	t <sub>off</sub>		_	130	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq 24$ V, $V_{GS}$ = 10 V, $I_D$ = 45 A	_	39	_	nC
Gate-source charge		Q <sub>gs</sub>		—	25	—	
Gate-drain ("miller") charge		Q <sub>gd</sub>		—	14	_	

#### Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	—	_	_	45	А
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	—	_	_	135	А
Forward voltage (diode)	V <sub>DSF</sub>	I <sub>DR</sub> = 45 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 45 \text{ A}, V_{GS} = 0 \text{ V},$	_	100	_	ns
Reverse recovery charge	Q <sub>rr</sub>	dI <sub>DR</sub> /dt = 50 A/μs		200		nC

## Marking



Note 4: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

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